



450V NPN HIGH VOLTAGE POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > 450V
- BV_{CES} > 700V
- BV_{EBO} > 9V
- I_C = 1.5A high Continuous Collector Current
- Integrated Collector-Emitter Diode to act as free-wheeling diode
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.112 grams (approximate)

Applications

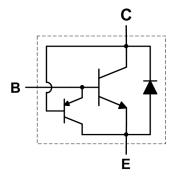
Low power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting

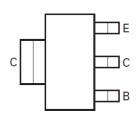




Top View







Top View Pin-Out

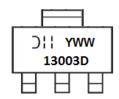
Ordering Information (Note 4)

Product	Package	Marking	Tape Width (mm)	Quantity
DXT13003DG-13	SOT223	DXT13003D	12	2,500

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



13003D = Product Type Marking Code YWW = Date Code Marking Y = Last Digit of the Year (ex: 3 =2013) WW = Week Code 01-52



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V _{BE} = 0V)	V _{CES}	700	V
Collector-Emitter Voltage	V _{CEO}	450	V
Emitter-Base Voltage	V _{EBO}	9	V
Continuous Collector Current	Ic	1.3	Α
Peak Pulse Collector Current	I _{CM}	3	Α
Continuous Base Current	I _B	0.75	Α
Peak Pulse Base Current	I _{BM}	1.5	A

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3		
Power Dissipation	(Note 6)	P_{D}	2	W	
	(Note 7)		0.7		
	(Note 5)	$R_{\theta JA}$	42		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	62.5	°C/W	
	(Note 7)	$R_{ heta JA}$	178		
Thermal Resistance Junction to Lead	(Note 8)	$R_{ heta JL}$	17		
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

ESD Ratings (Note 9)

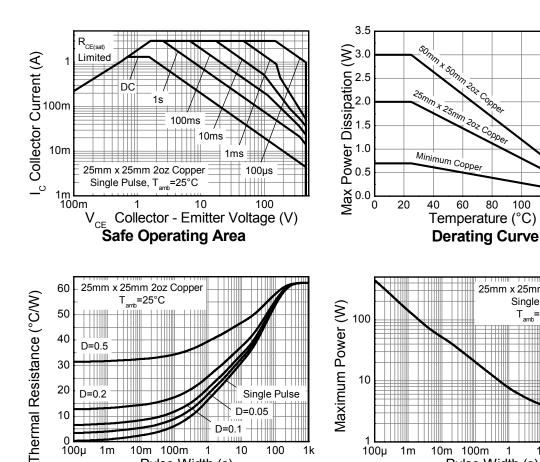
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under For a device mounted with the collector lead on summ x summ 2oz copper that is on a setill air conditions whilst operating in a steady-state.
 Same as note (5), except the device is mounted on 25mm x 25mm 2oz copper.
 Same as note (5), except the device is mounted on minimum recommended pad layout.
 Thermal resistance from junction to solder-point (at the end of the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Safe Operating Areas and Derating Information (@TA = +25°C, unless otherwise specified.)



10

100

100µ

10m 100m

Pulse Width (s)

Transient Thermal Impedance

Pulse Width (s) **Pulse Power Dissipation**

100m

120

25mm x 25mm 2oz Copper

Single Pulse

T_{amb}=25°C

10

100

160

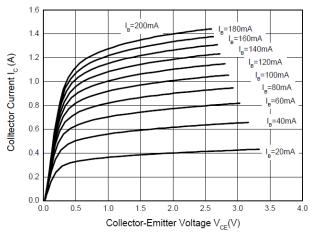


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

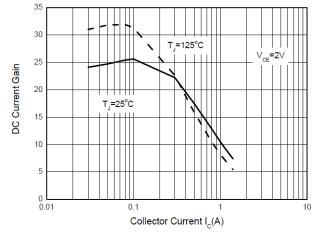
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Emitter Breakdown Voltage	BV_CES	700	I	-	V	$I_C = 100 \mu A, V_{BE} = 0 V$	
Collector-Emitter Breakdown Voltage	BV_CEO	450	=	-	V	I _C = 100μA	
Emitter-Base Breakdown Voltage	BV_{EBO}	9	-	-	V	I _E = 100μA	
Collector Cutoff Current	I _{CEV}	-	=	10	μA	V _{CE} = 700V, V _{BE} = -1.5V	
DC current transfer Static ratio (Note 10)	h _{FE}	20 16 5.0		40 30 25	-	I_C = 20mA, V_{CE} = 10V I_C = 0.5A, V_{CE} = 2V I_C = 1.0A, V_{CE} = 2V	
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}	-	-	0.3 0.4	V	$I_C = 0.5A$, $I_B = 0.1A$ $I_C = 1A$, $I_B = 0.25A$	
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	-	-	1.0 1.2	V	I _C = 0.5A, I _B = 0.1A I _C = 1A, I _B = 0.25A	
Output Capacitance	C _{ob}	-	18	-	pF	V _{CB} = 10V, f = 0.1MHz	
Transition Frequency	f _T	4	-	-	MHz	I _C = 0.1A, V _{CE} = 10V	
Turn-on Time with Resistive Load	t _{on}	-	-	0.7			
Storage Time with Resistive Load	ts	-	-	3.0	μs	$I_C = 1A, V_{CC} = 125V, I_{B1} = 0.2A,$ $I_{B2} = -0.2A$	
Fall Time with Resistive Load	t _f	=	=	0.35		IBZ0.2M	

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤2%.

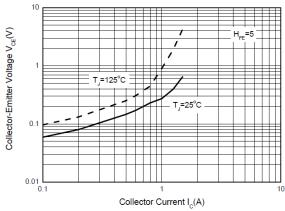
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



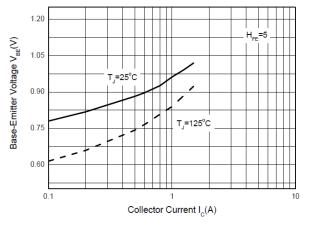
Static Characterstics



DC Current Gain



Collector-Emitter Saturation Region

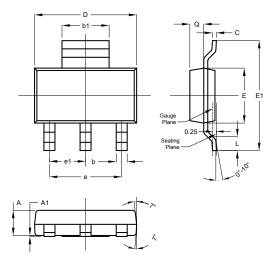


Base-Emitter Saturation Voltage



Package Outline Dimensions

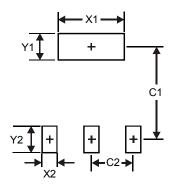
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	ı	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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